NSN 5962-01-263-1010

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level output and 23.00 nanoseconds propagation delay time, high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-263-1010
Body Length:
0.840 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
700.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
Quad 2 input
Design Function And Quantity:
4 transceiver
Case Outline Source And Designator:
D-2 mil-m-38510
Current Rating Per Characteristic:
30.00 milliamperes forward current, nonrepetitive, peak total value absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
18.00 nanoseconds propagation delay time, low to high level output and 23.00 nanoseconds propagation delay tim
output
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0

